



20V P-Channel Enhancement Mode MOSFET

Voltage

-20 V

Current

-7.2A

Features

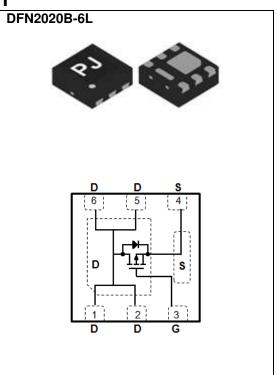
- $R_{DS(ON)}$, $V_{GS}@-4.5V$, $I_{D}@-7.2A<32m\Omega$
- $R_{DS(ON)}$, V_{GS} @-2.5V, I_{D} @-5.0A<39m Ω
- $R_{DS(ON)}$, V_{GS} @-1.8V, I_{D} @-2.5A<48m Ω
- Advanced Trench Process Technology
- High density cell design for ultra low on-resistance
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

• Case: DFN2020B-6L Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.0003 ounces, 0.0086 grams



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	-20	V	
Gate-Source Voltage		V _{GS}	<u>+</u> 8		
Continuous Drain Current (Note 4)		ID	-7.2	A	
Pulsed Drain Current (Note 1)		I _{DM}	-28.8		
Power Dissipation	T _a =25°C	P _D	2.8	W	
	Derate above 25°C		22	mW/°C	
Operating Junction and Storage Temperature Range		T _J ,T _{STG}	-55~150	°C	
Typical Thermal Resistance					
- Junction to Ambient, t<10s (Note 4,5)		Reja	44.6	°C/W	





Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	BV _{DSS} V _{GS} =0V, I _D =-250uA -20	-	-	V	
Gate Threshold Voltage	$V_{\text{GS(th)}}$	V _{DS} =V _{GS} , I _D =-250uA	-0.35	-0.6	-0.9	V
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-4.5V, I _D =-7.2A	-	25	32	mΩ
		V _{GS} =-2.5V, I _D =-5A	-	30	39	
		V _{GS} =-1.8V, I _D =-2.5A	-	35	48	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-16V, V _{GS} =0V	-	-	-1	uA
Gate-Source Leakage Current	Igss	$V_{GS}=\underline{+}8V, V_{DS}=0V$	-	-	<u>+</u> 100	nA
Dynamic (Note 6)						
Total Gate Charge	Q_g	V _{DS} =-10V, I _D =-7.2A, V _{GS} =-4.5V (Note 2,3)	-	18.9	-	nC
Gate-Source Charge	Q_gs		-	2.8	-	
Gate-Drain Charge	Q_gd		-	4.2	-	
Input Capacitance	Ciss	V _{DS} =-10V, V _{GS} =0V,	-	1785	-	pF
Output Capacitance	Coss		-	152	-	
Reverse Transfer Capacitance	Crss	f=1MHZ	-	125	-	
Turn-On Delay Time	td _(on)	V_{DS} =-10V, I_{D} =-7.2A, V_{GEN} =-4.5V, R_{L} =10 Ω	-	12	-	ns
Turn-On Rise Time	tr		-	68	-	
Turn-Off Delay Time	td _(off)		-	82	-	
Turn-Off Fall Time	tf	MG=012 (Note 2,0)	-	35	-	
Drain-Source Diode						
Maximum Continuous Drain-Source					1 5	А
Diode Forward Current	ls		-	-	-1.5	
Diode Forward Voltage	V _{SD}	I _S =-1A, V _G S=0V	-	-0.64	-1.2	V

NOTES:

- 1. Pulse width<300us, Duty cycle<2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature T_{J(MAX)}=150°C. Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.
- 4. The maximum current rating is package limited.
- 5. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing.





TYPICAL CHARACTERISTIC CURVES

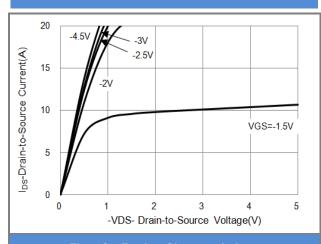


Fig.1 On-Region Characteristics

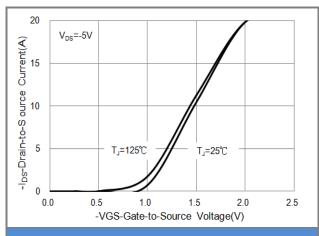


Fig.2 Transfer Characteristics

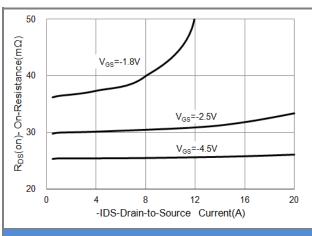


Fig.3 On-Resistance vs. Drain Current

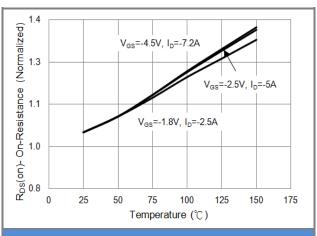
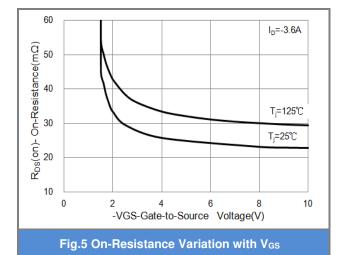
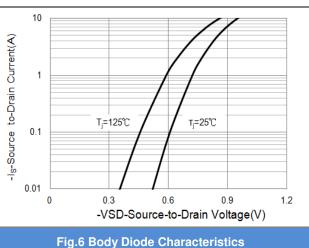


Fig.4 On-Resistance vs. Junction temperature









TYPICAL CHARACTERISTIC CURVES

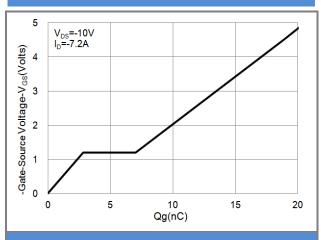


Fig.7 Gate-Charge Characteristics

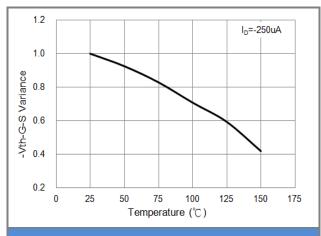


Fig.8 Threshold Voltage Variation with Temperature

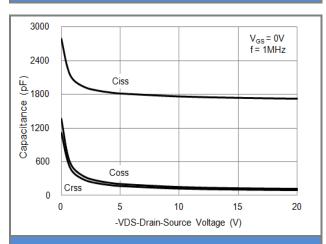


Fig.9 Capacitance vs. Drain-Source Voltage

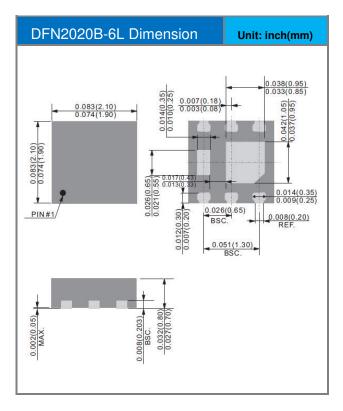


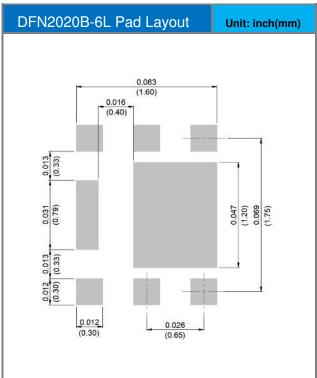


Part No. Packing Code Version

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJQ2405-AU_R1_000A1	DFN2020B-6L	3K pcs / 7" reel	405	Halogen free RoHS compliant

Packaging Information & Mounting Pad Layout









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